

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1089	hdp same trench with fill	US_PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2008/09/03 15:37
L2	648	hdp with trench with fill	US_PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2008/09/03 15:37
L3	332	hdp with trench with fill and silicon nitride and sti	US_PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2008/09/03 15:37
L4	44	hdp with teos with trench with fill and silicon nitride and sti	US_PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2008/09/03 15:59
L5	1	hdp with trench with fill and ozone teos with selective and silicon nitride and sti	US_PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2008/09/03 16:07
L6	1	hdp with trench with fill and ozone teos same selective and silicon nitride and sti	US_PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2008/09/03 16:07
L7	2	hdp same trench with fill and ozone teos same selective and silicon nitride and sti	US_PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2008/09/03 16:08

L8	536	hdp same trench with fill and silicon nitride and sti	US_PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2008/09/03 16:12
L9	0	("200200123206").PN.	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/09/03 16:25
L10	2	("20020123206").PN.	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/09/03 16:26
L11	2251	(438/424).OCLS.	US_PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/09/03 17:30
L12	1884	(438/427).OCLS.	US_PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/09/03 17:30
L13	737	(438/435).OCLS.	US_PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/09/03 17:30
L14	831	(257/e21.54).OCLS.	US_PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/09/03 17:30
S1	111	trench with selective adj grow\$3	US_PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2007/09/01 20:16

S2	0	trench with selective adj grow\$3 same second adj dielectric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2006/02/02 15:15
S3	111	trench with selective adj grow\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2006/02/02 15:26
S4	1	trench with selective adj grow\$3 with insulation	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2006/02/02 15:21
S5	5	trench with selective adj grow\$3 with dielectric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2006/02/02 15:30
S6	174	selective adj grow\$3 with dielectric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2006/02/02 15:30
S7	14	selective adj grow\$3 near dielectric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2006/02/02 19:39
S8	1	selective adj grow\$3 near insulator	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2006/02/02 15:30
S9	1669	(438/424).OCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/01 21:57

S10	1753	(438/427).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/01 21:57
S11	564	(438/435).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/01 21:57
S12	134	trench with dielectric with mask same known	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2006/08/05 01:14
S13	8	trench with deposit\$4 with dielectric with mask with known	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2006/08/05 01:15
S14	1799	(438/424).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/08/05 01:50
S15	1778	(438/427).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/08/05 01:50
S16	606	(438/435).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2006/08/05 01:50
S17	698	(257/e21.54).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/01 21:57

S18	708	(257/e21.54).OCLS.	US;PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/03/02 18:16
S19	2	("20040231588").PN.	US;PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/20 01:26
S20	7	teos with ozone same selective same trench and hdp	US;PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/08/20 01:33
S21	148	teos with ozone same trench and hdp	US;PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/08/20 01:50
S22	14	teos with ozone same selective\$3 same trench and hdp	US;PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/08/20 01:54
S23	20	teos with ozone same selective\$3 and trench and hdp	US;PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/08/20 01:57
S24	14	teos same ozone same selective\$3 same trench and trench and hdp	US;PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/08/20 01:58
S25	14	teos same ozone same selective\$3 same trench and hdp	US;PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/08/20 01:58

S26	6	teos same "o.sub.3" same selective\$3 same trench and hdp	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2007/08/20 01:58
S27	2	("20040253834").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/08/20 09:51
S28	2	("20020072198").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/01 20:18
S29	2	("20020168873").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/01 20:18
S30	2080	(438/424).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/01 21:57
S31	1840	(438/427).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/01 21:57
S32	677	(438/435).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/01 21:57
S33	716	(257/e21.54).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2007/09/01 21:57

S34	2	("20020072198").PN.	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/02/26 17:05
S35	0	selective deposition with ozone teos and hdp and trench and mask with silicon nitride	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/02/26 17:12
S36	31	ozone teos and hdp and trench and mask with silicon nitride	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/02/26 17:12
S37	1	"6410456".PN.	USPAT; USOCR	ADJ	ON	2008/02/26 17:26
S38	1	"6551925".PN.	USPAT; USOCR	ADJ	ON	2008/02/26 17:27
S39	74	ozone near teos and hdp and trench and mask with silicon nitride	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/02/26 17:29
S40	2	ozone near teos same lower and hdp and trench and mask with silicon nitride	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/02/26 17:30
S41	0	ozone near teos same lower same trench and aspect ration	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/02/26 17:34
S42	10	ozone near teos same lower same trench and aspect ratio	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/02/26 17:34
S43	0	cur\$3 with compact\$3 with sog with known	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/02/26 18:00

S44	1	cur\$3 with compact\$3 with sog	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/02/26 18:01
S45	1860	(438/427).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/02/26 18:10
S46	2162	(438/424).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/02/26 18:10
S47	700	(438/435).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/02/26 18:10
S48	761	(257/e21.54).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/02/26 18:10
S49	21	teos with ozone same selective\$3 and trench and hdp	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/02/26 18:10
S50	12	trench with selective adj grow\$3 with silicon oxide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2008/06/14 21:08
S51	17	trench same selective adj grow\$3 with silicon oxide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2008/06/14 21:16

S52	33	selox	US_PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2008/06/14 21:20
S53	14	selox and trench	US_PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	ADJ	OFF	2008/06/14 21:20
S54	2	"20020072198"	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2008/06/14 23:06
S55	2210	(438/424).CCLS.	US_PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/06/16 19:51
S56	1871	(438/427).CCLS.	US_PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/06/16 19:52
S57	718	(438/435).CCLS.	US_PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/06/16 19:52
S58	791	(257/e21.54).OCLS.	US_PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/06/16 19:52
S59	2	("20020072198").PN.	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/08/25 18:05

9/3/2008 5:30:59 PM

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